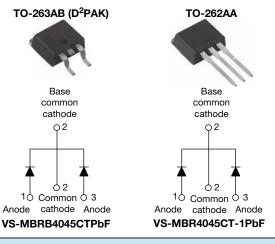
VS-MBRB4045CTPbF, VS-MBR4045CT-1PbF www.vishay.com

Vishay Semiconductors

epoxy

High Performance Schottky Rectifier, 2 x 20 A



PRODUCT SUMMARY						
Package	TO-263AB (D ² PAK), TO-262AA					
I _{F(AV)}	40 A					
V _R	45 V					
V _F at I _F	0.58 V					
I _{RM} max.	95 mA at 125 °C					
T _J max.	150 °C					
Diode variation	Common cathode					
E _{AS}	20 mJ					

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- · High frequency operation
- Center tap TO-220, D²PAK and TO-262 packages

encapsulation for enhanced mechanical

• High purity, high temperature



- strength and moisture resistance · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	Rectangular waveform (per device)	vaveform (per device) 40						
I _{FRM}	T _C = 118 °C (per leg)	40	A					
V _{RRM}		45	V					
I _{FSM}	t _p = 5 μs sine	900	A					
V _F	20 A _{pk} , T _J = 125 °C	0.58	V					
TJ	Range	-65 to +150	°C					

VOLTAGE RATINGS							
PARAMETER SYMBOL VS-MBRB4045CTPbF VS-MBR4045CT-1PbF UNITS							
Maximum DC reverse voltage	V _R	45	V				
Maximum working peak reverse voltage	V _{RWM}	45	V				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	PARAMETER SYMBOL TEST CONDITIONS			VALUES	UNITS			
Maximum average per leg		$T_{\rm C}$ = 118 °C, rated V _R				20		
forward current per device	I _{F(AV)}			40				
Peak repetitive forward current per leg	I _{FRM}	Rated V_R , square wave, 20 kHz, $T_C = 118 \text{ °C}$		40	А			
Maximum peak one cycle non-repetitive		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	900				
peak surge current per leg	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	210				
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 4.4 mH		20	mJ			
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero Frequency limited by T _J maximu		3	А			

Revision: 15-Jul-14

Document Number: 94311

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000

1



www.vishay.com

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS		
		20 A	T _J = 25 °C	0.60	V		
Maximum forward voltage drop	V _{FM} ⁽¹⁾	40 A	1] = 23 0	0.78			
Maximum forward voltage drop	¥FM \''	20 A	T _{.1} = 125 °C	0.58			
		40 A	1j = 125 0	0.75			
•• • • • •	I _{RM} ⁽¹⁾	$T_J = 25 \ ^\circ C$		1	mA		
Maximum instantaneous reverse current		T _J = 100 °C	Rated DC voltage	50			
		T _J = 125 °C		95			
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range	900	pF			
Typical series inductance	L _S	Measured from top of terr	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs		

Note

 $^{(1)}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

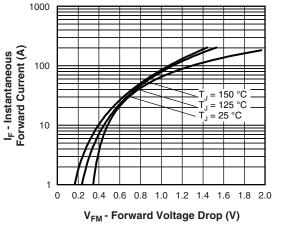
THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction temperature range	TJ		-65 to +150	°C			
Maximum storage temperature range	T _{Stg}		-65 to +175	U			
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	1.5				
Typical thermal resistance, case to heatsink	R _{thCS}	R _{thCS} Mounting surface, smooth and greased (Only for TO-220)		°C/W			
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation (For D ² PAK and TO-262)	50				
Approvimate weight			2	g			
Approximate weight			0.07	oz.			
Mounting torgue		Non-lubricated threads	6 (5)	kgf · cm			
Mounting torque maximum		Non-lubricated threads	12 (10)	(lbf · in)			
Marking device		Case style D ² PAK	MBRB4	045CT			
Marking device		Case style TO-262	MBR40	45CT-1			

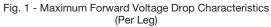
2

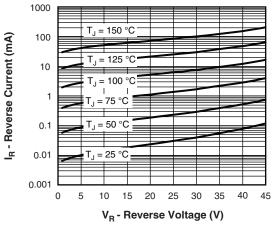


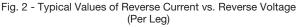
VS-MBRB4045CTPbF, VS-MBR4045CT-1PbF

Vishay Semiconductors









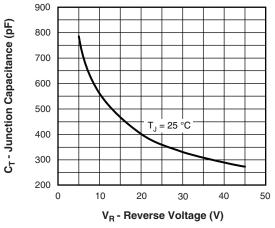


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

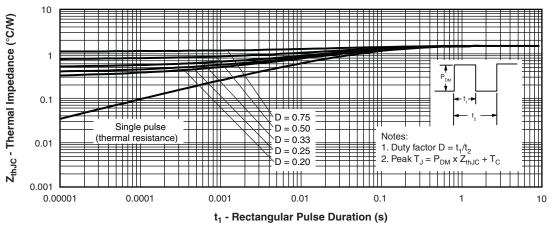
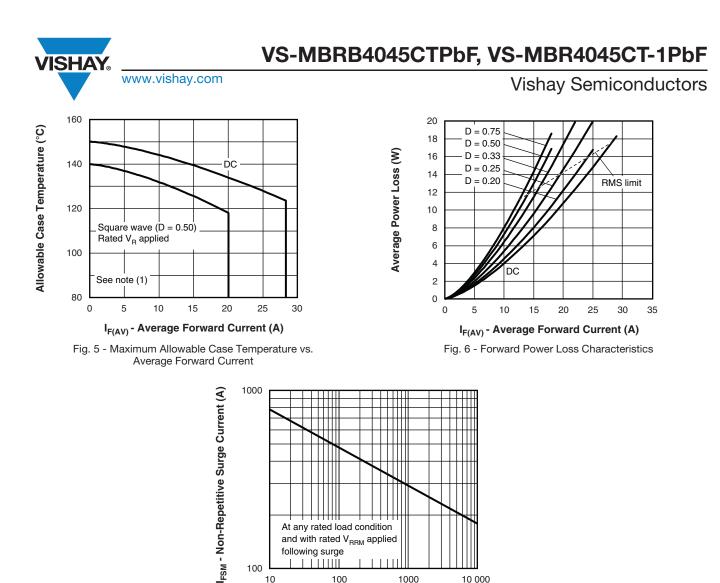


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

Revision: 15-Jul-14

3

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



following surge 1 | | | | | |

100

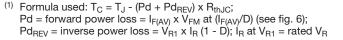
t_p - Square Wave Pulse Duration (μs) Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

1000

10 000

100

10



Note

www.vishay.com

VS-MBRB4045CTPbF, VS-MBR4045CT-1PbF

Vishay Semiconductors

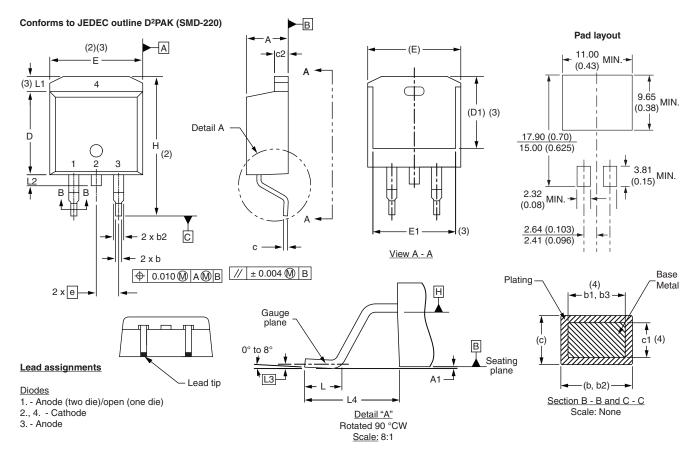
ORDERING INFORMATION TABLE

Device code	VS-	MBR	В	40	45	СТ	-1	TRL	PbF
		2	3	4	5	6	7	8	9
	1 · · · · · · · · · · · · · · · · · · ·	- Ess - B - Nu - Cur - Volt - CT - Nu 1	ential pa = D ² PA one = Tr rent rati tage rati = esser one = D = TO-2	O-262 [ng (40 = ng (45 = tial part ² PAK [7 Noi 7 = 40 A) = 45 V) numbe 3 = B 3 Noi	ne 1 r			
	9	• Ti - • Pi	RR = tap bF = lea	e and re be and r d (Pb)-f Pb)-free	eel (righ ree (for	nt orient TO-262	ed - for 2 and D ²	D ² PAK ² PAK tu	only)

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95014					
Part marking information	www.vishay.com/doc?95008					
Packaging information	www.vishay.com/doc?95032					
SPICE model	www.vishay.com/doc?95296					

Vishay Semiconductors

D²PAK, TO-262



DIMENSIONS - D²PAK in millimeters and inches

SHA

SYMBOL	MILLIMETERS		INC	INCHES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
с	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

(7) Outline conforms to JEDEC outline TO-263AB

Notes

 $^{(1)}\,$ Dimensioning and tolerancing per ASME Y14.5 M-1994 $\,$

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- ⁽⁴⁾ Dimension b1 and c1 apply to base metal only
- ⁽⁵⁾ Datum A and B to be determined at datum plane H
- ⁽⁶⁾ Controlling dimension: inch

Document Number: 95014 Revision: 31-Mar-09 For technical questions within your region, please contact one of the following: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u>

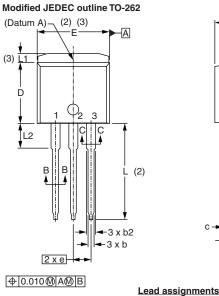
Outline Dimensions

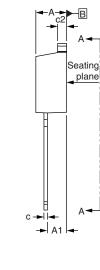
Vishay Semiconductors

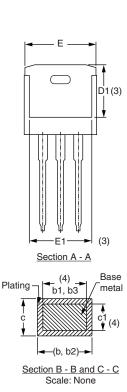
D²PAK, TO-262



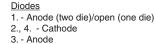
DIMENSIONS - TO-262 in millimeters and inches

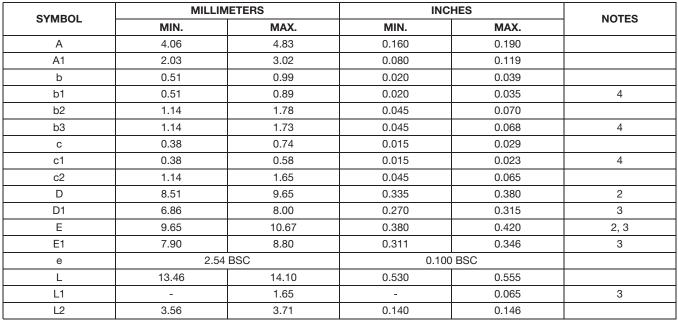






Lead tip





Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- ⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- ⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1
- ⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.